Thyristor Semiconductor Device - Page 1 of 1



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	closure Material:
Ce	eramic
0	verall Length:
Be	tween 1.000 inches and 1.065 inches
0	verall Diameter:
Be	tween 2.200 inches and 2.500 inches
Me	ounting Method:
Pr	ess fit
Fe	atures Provided:
He	ermetically sealed case
Se	emiconductor Material:
Sil	icon
Vc	oltage Rating In Volts Per Characteristic:
12	00.0 repetitive peak off-state voltage and 1200.0 repetitive peak reverse voltage and 1400.0 nonrepetitive peak reverse voltage
Сι	Irrent Rating Per Characteristic:
13	000.00 amperes peak forward surge current nanoamperes
Pc	ower Rating Per Characteristic:
20	0.0 watts small-signal input power, common-collector blank and 5.0 watts small-signal input power, common-collector horsepower metri
Ma	aximum Operating Tempurature Per Measurement Point:
12	5.0 degrees celsius junction
Те	rminal Type And Quantity:
2 ι	uninsulated wire lead w/terminal lug and 2 case
Sł	nelf Life:
N/	a
Ur	nit Of Measure:
De	emilitarization:
No	
Fii	g:
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